# NSN 5961-01-349-0223

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Inclosure Material:

Ceramic and metal

**Overall Length:** 

10.55 millimeters

Terminal Length:

4.0 millimeters

**Overall Width:** 

10.55 millimeters

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

-20.0 collector to base voltage/static/emitter open and -12.0 collector to emitter voltage/static/base open and -3.0 emitter to base voltage, static, collector open

Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-collector preset

Transfer Ratio:

20.0 static forward current transfer ratio, common-emitter and 200.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: pnp

### Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

### Unit Of Measure:

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Demilitarization:

No

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